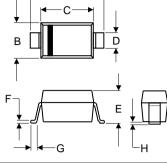


BAV19W, BAV20W, BAV21W Silicon Epitaxial Planar Diodes

Features

- * High Voltage Switching Diode
- * Fast switching speed
- * Surface mount package ideally suited for automatic insertion
- * Marking Code: JX









SOD-123					
DIM	INCHES		MM		
	MIN	MAX	MIN	MAX	
Α	0.138	0.150	3.50	3.80	
В	0.059	0.067	1.50	1.70	
С	0.100	0.106	2.54	2.70	
D	0.020	0.028	0.50	0.70	
E	0.036	0.048	0.91	1.21	
F	0.003	0.008	0.08	0.20	
G	0.008	0.016	0.20	0.40	
Н		0.004		0.10	

Maximum Ratings (T_A=25 °C unless otherwise noted)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage BAV19W BAV20W BAV21W	Vrrm	120 200 250	V
Reverse Voltage BAV19W BAV20W BAV21W	VR	100 150 200	V
Average Rectified Forward Current	I F(AV)	200	mA
Forward Continuous Current	Iғм	400	mA
Repetitive Peak Forward Current	IFRM	625	mA
Non-repetitive Peak Forward Surge Current at t = 1 ms at t = 1 s	Ігэм	2.5 0.5	А
Power Dissipation	Pd	250	mW
Operating and Storage Temperature Range	T_j/T_{stg}	- 65 to + 150	${\mathbb C}$

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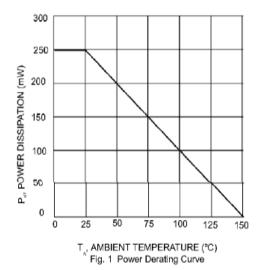


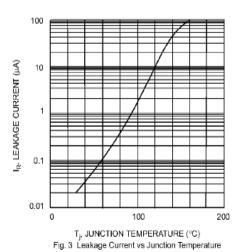
BAV19W, BAV20W, BAV21W Silicon Epitaxial Planar Diodes

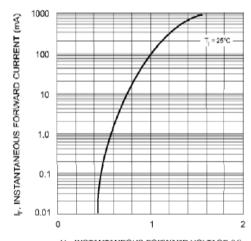
Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter		Symbol	Min.	Max.	Unit
Forward Voltage at IF = 100 mA at IF = 200 mA		VF	-	1 1.25	V
Reverse Breakdown Voltage at I _R = 100 µA BAV19W BAV20W BAV21W		V(BR)R	120 200 250		V
Reverse Current at V _R = 100 V at V _R = 150 V at V _R = 200 V	BAV19W BAV20W BAV21W	lR	- - -	100 100 100	nA
Total Capacitance at $V_R = 0$, $f = 1$ MHz		Ст	-	5	pF
Reverse Recovery Time at I _F = I _R = 30 mA, I _{rr} = 0.1I _R , R _L = 100 Ω		trr	-	50	ns

Ratings and Characteristic Curves







V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics

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BAV19W, BAV20W, BAV21W Silicon Epitaxial Planar Diodes

Ordering Information

Part No.	Package	Packing Code	Packing
BAV19W, BAV20W, BAV21W	SOD-123	R30	3000pcs/Reel

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